

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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Not recommended  
for new design

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BIPOLAR ANALOG INTEGRATED CIRCUIT  
**μPC78L00 SERIES**

**THREE TERMINAL POSITIVE VOLTAGE REGULATORS**

**DESCRIPTION**

The μPC78L00 series are monolithic three terminal positive regulators which employ internally current limiting, thermal shut down, output transistor safe area protection make them essentially indestructible.

They are intended as fixed voltage regulators in a wide range of application including local on card regulation for elimination of distribution problems associated wide single point regulation.

**FEATURES**

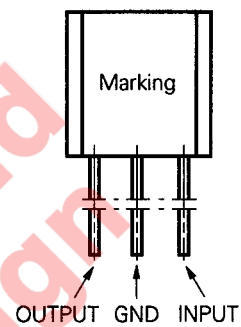
- Output current in excess of 100 mA.
- Low noise.
- High Ripple Rejection.
- Internal output transistor safe area protection.
- Internal thermal overload protection.
- Internal short circuit current limiting.

**ORDER INFORMATION**

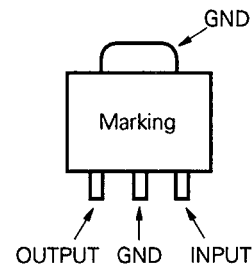
Type Number	Output Voltage	Package	Quality Grade
μPC78L05J	5 V	TO-92	Standard
μPC78L05T		SOT-89	
μPC78L06J	6 V	TO-92	
μPC78L06T		SOT-89	
μPC78L07J	7 V	TO-92	
μPC78L07T		SOT-89	
μPC78L08J	8 V	TO-92	
μPC78L08T		SOT-89	
μPC78L10J	10 V	TO-92	
μPC78L10T		SOT-89	
μPC78L12J	12 V	TO-92	
μPC78L12T		SOT-89	
μPC78L15J	15 V	TO-92	
μPC78L15T		SOT-89	

**CONNECTION DIAGRAM**

μPC78L00J Series

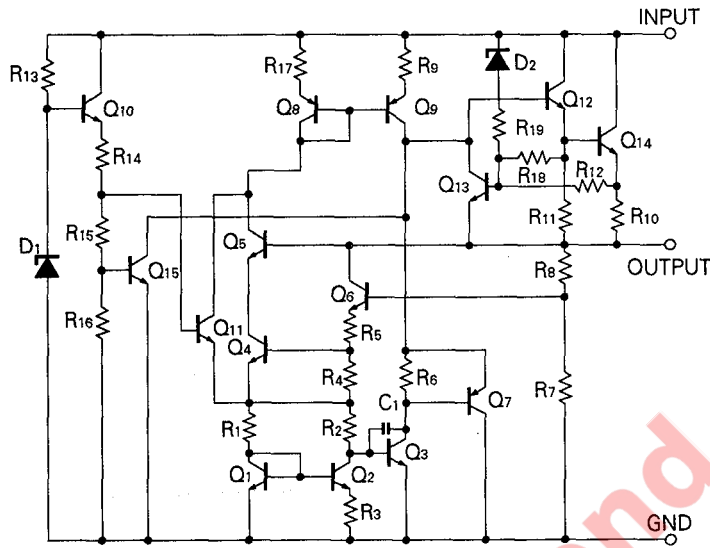


μPC78L00T Series



Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

EQUIVALENT CIRCUIT



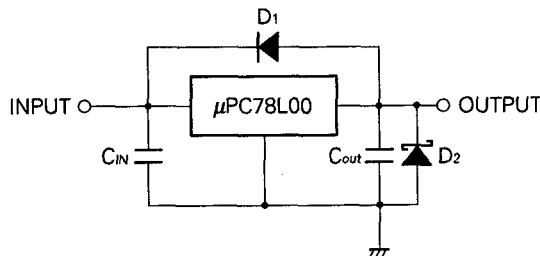
ABSOLUTE MAXIMUM RATINGS (T<sub>a</sub> = 25 °C)

PARAMETER	SYMBOL	RATINGS		UNIT
		μPC78L00J Series	μPC78L00T Series	
Input Voltage	V <sub>IN</sub>	30/35 (Note1)		V
Internal Power Dissipation	P <sub>T</sub>	700	400/2000 (Note2)	mW
Operating Ambient Temperature Range	T <sub>opt</sub>	-20 to +85		°C
Operating Junction Temperature Range	T <sub>opt(j)</sub>	-20 to +150		°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150		°C
Thermal Resistance (junction to ambient)	R <sub>th(j-a)</sub>	180	315/62.5 (Note2)	°C/W

(Note 1) μPC78L05, 06, 07, 08 : 30 V, μPC78L10, 12, 15 : 35 V

(Note 2) with 2.5 cm<sup>2</sup> × 0.7 mm ceramic substrate

TYPICAL CONNECTION



C1: Required if regulator is located an appreciable distance from power supply filter

C2: More than 0.1 μF

D1: Needed for V<sub>IN</sub> < V<sub>o</sub>

D2: Needed for V<sub>o</sub> < GND

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	TYPE NUMBER	MIN.	TYP.	MAX.	UNIT
Input Voltage	V <sub>IN</sub>	μPC78L05	7	10	20	V
		μPC78L06	8.5	11	21	
		μPC78L07	9.5	12	22	
		μPC78L08	10.5	14	23	
		μPC78L10	12.5	17	25	
		μPC78L12	14.5	19	27	
		μPC78L15	17.5	23	30	
Output Current	I <sub>o</sub>	All	0	40	70	mA
Operating Temperature Range	T <sub>opt</sub>	All	-20		+85	°C
Operating Junction Temperature Range	T <sub>opt(j)</sub>	All	-20		+125	°C

ELECTRICAL CHARACTERISTICS μPC78L05

(V<sub>IN</sub> = 10 V, I<sub>o</sub> = 40 mA, 0 °C ≤ T<sub>j</sub> ≤ + 125 °C, C<sub>IN</sub> = 0.33 μF, C<sub>OUT</sub> = 0.1 μF)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	V <sub>o</sub>	T <sub>j</sub> = 25 °C	4.8	5.0	5.2	V
		7 V ≤ V <sub>IN</sub> ≤ 20 V, 1 mA ≤ I <sub>o</sub> ≤ 40 mA	4.75		5.25	
		V <sub>IN</sub> = 10 V, 1 mA ≤ I <sub>o</sub> ≤ 70 mA	4.75		5.25	
Line Regulation	REG <sub>IN</sub>	T <sub>j</sub> = 25 °C, 7 V ≤ V <sub>IN</sub> ≤ 20 V		6	150	mV
		T <sub>j</sub> = 25 °C, 8 V ≤ V <sub>IN</sub> ≤ 20 V		4	100	
Load Regulation	REG <sub>L</sub>	T <sub>j</sub> = 25 °C, 1 mA ≤ I <sub>o</sub> ≤ 100 mA		9	60	mV
		T <sub>j</sub> = 25 °C, 1 mA ≤ I <sub>o</sub> ≤ 40 mA		4	30	
Quiescent Current	I <sub>BIAS</sub>	T <sub>j</sub> = 25 °C		2.3	5.5	mA
Quiescent Current Change	ΔI <sub>BIAS</sub>	8 V ≤ V <sub>IN</sub> ≤ 20 V, I <sub>o</sub> = 40 mA			1.5	mA
		V <sub>IN</sub> = 10 V, 1 mA ≤ I <sub>o</sub> ≤ 40 mA			0.1	
Output Noise Voltage	V <sub>n</sub>	T <sub>j</sub> = 25 °C, 10 Hz ≤ f ≤ 100 kHz		45	120	μV <sub>r.m.s.</sub>
Ripple Rejection	R · R	T <sub>j</sub> = 25 °C, f = 120 Hz, 8 V ≤ V <sub>IN</sub> ≤ 18 V	55	75		dB
Dropout Voltage	V <sub>DIF</sub>	T <sub>j</sub> = 25 °C		1.7		V
Short Circuit Current	I <sub>o(Short)</sub>	T <sub>j</sub> = 25 °C, V <sub>IN</sub> = 20 V		88		mA
Peak Output Current	I <sub>o(peak)</sub>	T <sub>j</sub> = 25 °C	125	160	205	mA
Temperature coefficient of Output Voltage	ΔV <sub>o</sub> /ΔT	I <sub>o</sub> = 5 mA		0.4		mV/°C

**ELECTRICAL CHARACTERISTICS μPC78L06**

( $V_{IN} = 11\text{ V}$ ,  $I_o = 40\text{ mA}$ ,  $0\text{ °C} \leq T_j \leq +125\text{ °C}$ ,  $C_{IN} = 0.33\text{ }\mu\text{F}$ ,  $C_{OUT} = 0.1\text{ }\mu\text{F}$ )

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	$V_o$	$T_j = 25\text{ °C}$	5.76	6.0	6.24	V
		$8.5\text{ V} \leq V_{IN} \leq 21\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$	5.70		6.30	
		$V_{IN} = 11\text{ V}$ , $1\text{ mA} \leq I_o \leq 70\text{ mA}$	5.70		6.30	
Line Regulation	REG <sub>IN</sub>	$T_j = 25\text{ °C}$ , $8.5\text{ V} \leq V_{IN} \leq 21\text{ V}$		6	155	mV
		$T_j = 25\text{ °C}$ , $9\text{ V} \leq V_{IN} \leq 21\text{ V}$		4	105	
Load Regulation	REG <sub>L</sub>	$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 100\text{ mA}$		10	65	mV
		$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$		4	35	
Quiescent Current	I <sub>BIAS</sub>	$T_j = 25\text{ °C}$		2.3	5.5	mA
Quiescent Current Change	$\Delta I_{BIAS}$	$9\text{ V} \leq V_{IN} \leq 21\text{ V}$ , $I_o = 40\text{ mA}$			1.5	mA
		$V_{IN} = 11\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$			0.1	
Output Noise Voltage	$V_n$	$T_j = 25\text{ °C}$ , $10\text{ Hz} \leq f \leq 100\text{ kHz}$		55	145	μV <sub>r.m.s.</sub>
Ripple Rejection	R · R	$T_j = 25\text{ °C}$ , $f = 120\text{ Hz}$ , $9\text{ V} \leq V_{IN} \leq 19\text{ V}$	54	75		dB
Dropout Voltage	V <sub>DIF</sub>	$T_j = 25\text{ °C}$		1.7		V
Short Circuit Current	I <sub>o</sub> short	$T_j = 25\text{ °C}$ , $V_{IN} = 21\text{ V}$		85		mA
Peak Output Current	I <sub>o</sub> peak	$T_j = 25\text{ °C}$	125	160	205	mA
Temperature coefficient of Output Voltage	$\Delta V_o/\Delta T$	$I_o = 5\text{ mA}$		0.5		mV/°C

**ELECTRICAL CHARACTERISTICS μPC78L07**

( $V_{IN} = 12\text{ V}$ ,  $I_o = 40\text{ mA}$ ,  $0\text{ °C} \leq T_j \leq +125\text{ °C}$ ,  $C_{IN} = 0.33\text{ }\mu\text{F}$ ,  $C_{OUT} = 0.1\text{ }\mu\text{F}$ )

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	$V_o$	$T_j = 25\text{ °C}$	6.72	7.0	7.28	V
		$9.5\text{ V} \leq V_{IN} \leq 22\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$	6.65		7.35	
		$V_{IN} = 12\text{ V}$ , $1\text{ mA} \leq I_o \leq 70\text{ mA}$	6.65		7.35	
Line Regulation	REG <sub>IN</sub>	$T_j = 25\text{ °C}$ , $9.5\text{ V} \leq V_{IN} \leq 22\text{ V}$		8	165	mV
		$T_j = 25\text{ °C}$ , $10\text{ V} \leq V_{IN} \leq 22\text{ V}$		5	115	
Load Regulation	REG <sub>L</sub>	$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 100\text{ mA}$		12	75	mV
		$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$		5	35	
Quiescent Current	I <sub>BIAS</sub>	$T_j = 25\text{ °C}$		2.3	5.5	mA
Quiescent Current Change	$\Delta I_{BIAS}$	$10\text{ V} \leq V_{IN} \leq 22\text{ V}$ , $I_o = 40\text{ mA}$			1.5	mA
		$V_{IN} = 12\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$			0.1	
Output Noise Voltage	$V_n$	$T_j = 25\text{ °C}$ , $10\text{ Hz} \leq f \leq 100\text{ kHz}$		70	180	μV <sub>r.m.s.</sub>
Ripple Rejection	R · R	$T_j = 25\text{ °C}$ , $f = 120\text{ Hz}$ , $10\text{ V} \leq V_{IN} \leq 20\text{ V}$	52	74		dB
Dropout Voltage	V <sub>DIF</sub>	$T_j = 25\text{ °C}$		1.7		V
Short Circuit Current	I <sub>o</sub> short	$T_j = 25\text{ °C}$ , $V_{IN} = 22\text{ V}$		83		mA
Peak Output Current	I <sub>o</sub> peak	$T_j = 25\text{ °C}$	125	160	205	mA
Temperature coefficient of Output Voltage	$\Delta V_o/\Delta T$	$I_o = 5\text{ mA}$		0.6		mV/°C

**ELECTRICAL CHARACTERISTICS μPC78L08**

( $V_{IN} = 14\text{ V}$ ,  $I_o = 40\text{ mA}$ ,  $0\text{ °C} \leq T_j \leq +125\text{ °C}$ ,  $C_{IN} = 0.33\text{ }\mu\text{F}$ ,  $C_{OUT} = 0.1\text{ }\mu\text{F}$ )

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	$V_o$	$T_j = 25\text{ °C}$	7.7	8.0	8.3	V
		$10.5\text{ V} \leq V_{IN} \leq 23\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$	7.6		8.4	
		$V_{IN} = 14\text{ V}$ , $1\text{ mA} \leq I_o \leq 70\text{ mA}$	7.6		8.4	
Line Regulation	$REG_{IN}$	$T_j = 25\text{ °C}$ , $10.5\text{ V} \leq V_{IN} \leq 23\text{ V}$		10	175	mV
		$T_j = 25\text{ °C}$ , $11\text{ V} \leq V_{IN} \leq 23\text{ V}$		6	125	
Load Regulation	$REG_L$	$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 100\text{ mA}$		14	80	mV
		$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$		6	40	
Quiescent Current	$I_{BIAS}$	$T_j = 25\text{ °C}$		2.4	5.5	mA
Quiescent Current Change	$\Delta I_{BIAS}$	$12\text{ V} \leq V_{IN} \leq 23\text{ V}$ , $I_o = 40\text{ mA}$			1.5	mA
		$V_{IN} = 14\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$			0.1	
Output Noise Voltage	$V_n$	$T_j = 25\text{ °C}$ , $10\text{ Hz} \leq f \leq 100\text{ kHz}$		85	190	$\mu\text{V}_{r.m.s.}$
Ripple Rejection	$R \cdot R$	$T_j = 25\text{ °C}$ , $f = 120\text{ Hz}$ , $12\text{ V} \leq V_{IN} \leq 22\text{ V}$	51	73		dB
Dropout Voltage	$V_{DIF}$	$T_j = 25\text{ °C}$		1.7		V
Short Circuit Current	$I_{o\text{short}}$	$T_j = 25\text{ °C}$ , $V_{IN} = 23\text{ V}$		80		mA
Peak Output Current	$I_{o\text{peak}}$	$T_j = 25\text{ °C}$	125	160	205	mA
Temperature coefficient of Output Voltage	$\Delta V_o / \Delta T$	$I_o = 5\text{ mA}$		0.6		mV/°C

**ELECTRICAL CHARACTERISTICS μPC78L10**

( $V_{IN} = 17\text{ V}$ ,  $I_o = 40\text{ mA}$ ,  $0\text{ °C} \leq T_j \leq +125\text{ °C}$ ,  $C_{IN} = 0.33\text{ }\mu\text{F}$ ,  $C_{OUT} = 0.1\text{ }\mu\text{F}$ )

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	$V_o$	$T_j = 25\text{ °C}$	9.6	10	10.4	V
		$12.5\text{ V} \leq V_{IN} \leq 25\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$	9.5		10.5	
		$V_{IN} = 17\text{ V}$ , $1\text{ mA} \leq I_o \leq 70\text{ mA}$	9.5		10.5	
Line Regulation	$REG_{IN}$	$T_j = 25\text{ °C}$ , $12.5\text{ V} \leq V_{IN} \leq 25\text{ V}$		12	200	mV
		$T_j = 25\text{ °C}$ , $13\text{ V} \leq V_{IN} \leq 25\text{ V}$		8	150	
Load Regulation	$REG_L$	$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 100\text{ mA}$		18	90	mV
		$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$		8	45	
Quiescent Current	$I_{BIAS}$	$T_j = 25\text{ °C}$		2.5	5.5	mA
Quiescent Current Change	$\Delta I_{BIAS}$	$13\text{ V} \leq V_{IN} \leq 25\text{ V}$ , $I_o = 40\text{ mA}$			1.5	mA
		$V_{IN} = 17\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$			0.1	
Output Noise Voltage	$V_n$	$T_j = 25\text{ °C}$ , $10\text{ Hz} \leq f \leq 100\text{ kHz}$		100	230	$\mu\text{V}_{r.m.s.}$
Ripple Rejection	$R \cdot R$	$T_j = 25\text{ °C}$ , $f = 120\text{ Hz}$ , $14\text{ V} \leq V_{IN} \leq 24\text{ V}$	49	69		dB
Dropout Voltage	$V_{DIF}$	$T_j = 25\text{ °C}$		1.7		V
Short Circuit Current	$I_{o\text{short}}$	$T_j = 25\text{ °C}$ , $V_{IN} = 25\text{ V}$		70		mA
Peak Output Current	$I_{o\text{peak}}$	$T_j = 25\text{ °C}$	125	160	205	mA
Temperature coefficient of Output Voltage	$\Delta V_o / \Delta T$	$I_o = 5\text{ mA}$		0.8		mV/°C

**ELECTRICAL CHARACTERISTICS μPC78L12**

( $V_{IN} = 19\text{ V}$ ,  $I_o = 40\text{ mA}$ ,  $0\text{ °C} \leq T_j \leq +125\text{ °C}$ ,  $C_{IN} = 0.33\text{ }\mu\text{F}$ ,  $C_{OUT} = 0.1\text{ }\mu\text{F}$ )

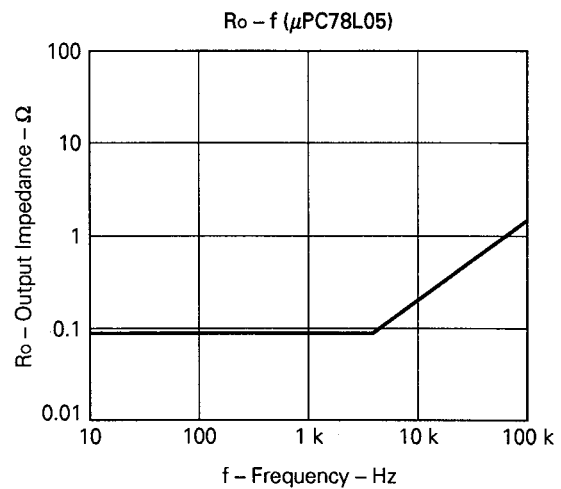
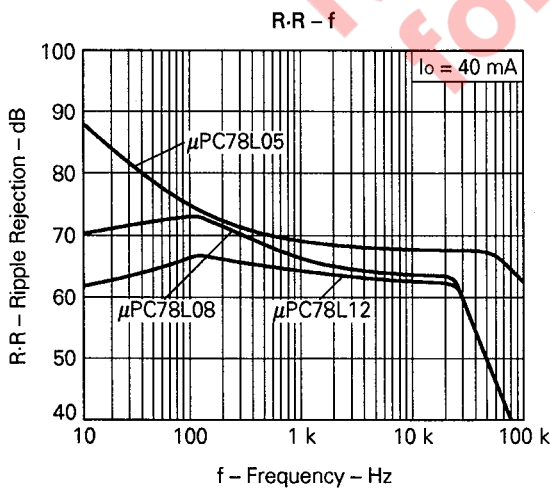
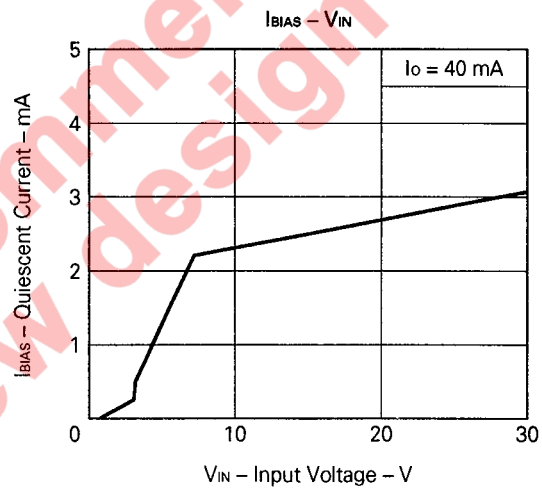
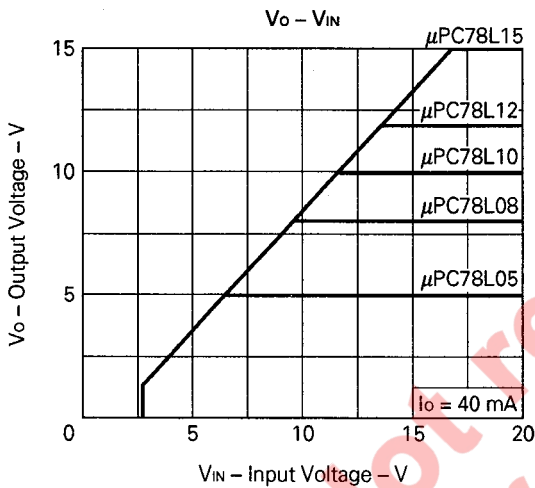
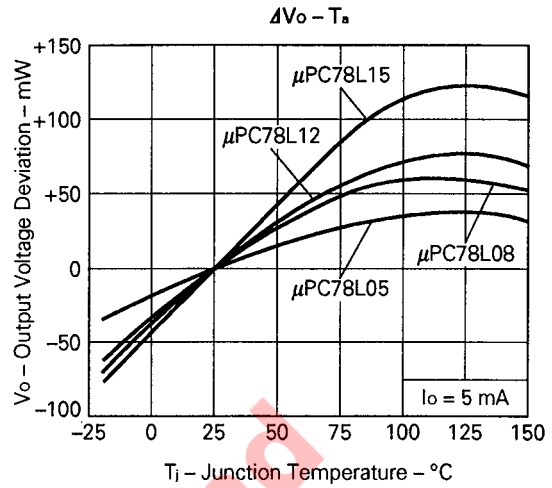
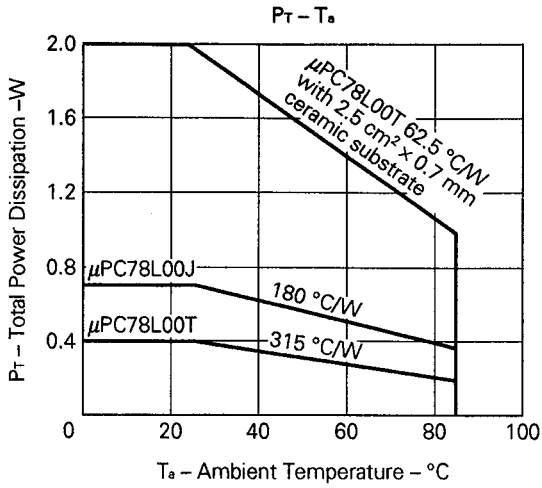
CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	$V_o$	$T_j = 25\text{ °C}$	11.5	12	12.5	V
		$14\text{ V} \leq V_{IN} \leq 27\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$	11.4		12.6	
		$V_{IN} = 19\text{ V}$ , $1\text{ mA} \leq I_o \leq 70\text{ mA}$	11.4		12.6	
Line Regulation	REG <sub>IN</sub>	$T_j = 25\text{ °C}$ , $14.5\text{ V} \leq V_{IN} \leq 27\text{ V}$		14	250	mV
		$T_j = 25\text{ °C}$ , $16\text{ V} \leq V_{IN} \leq 27\text{ V}$		10	200	
Load Regulation	REG <sub>L</sub>	$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 100\text{ mA}$		20	100	mV
		$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$		10	50	
Quiescent Current	$I_{BIAS}$	$T_j = 25\text{ °C}$		2.6	5.5	mA
Quiescent Current Change	$\Delta I_{BIAS}$	$16\text{ V} \leq V_{IN} \leq 27\text{ V}$ , $I_o = 40\text{ mA}$			1.5	mA
		$V_{IN} = 19\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$			0.1	
Output Noise Voltage	$V_n$	$T_j = 25\text{ °C}$ , $10\text{ Hz} \leq f \leq 100\text{ kHz}$		115	280	μV <sub>r.m.s.</sub>
Ripple Rejection	R · R	$T_j = 25\text{ °C}$ , $f = 120\text{ Hz}$ , $15\text{ V} \leq V_{IN} \leq 25\text{ V}$	47	66		dB
Dropout Voltage	$V_{DIF}$	$T_j = 25\text{ °C}$		1.7		V
Short Circuit Current	$I_{Oshort}$	$T_j = 25\text{ °C}$ , $V_{IN} = 27\text{ V}$		64		mA
Peak Output Current	$I_{Opeak}$	$T_j = 25\text{ °C}$	125	160	205	mA
Temperature coefficient of Output Voltage	$\Delta V_o / \Delta T$	$I_o = 5\text{ mA}$		1.1		mV/°C

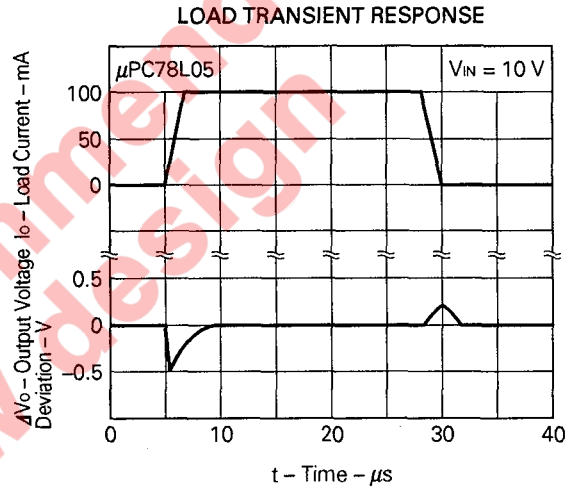
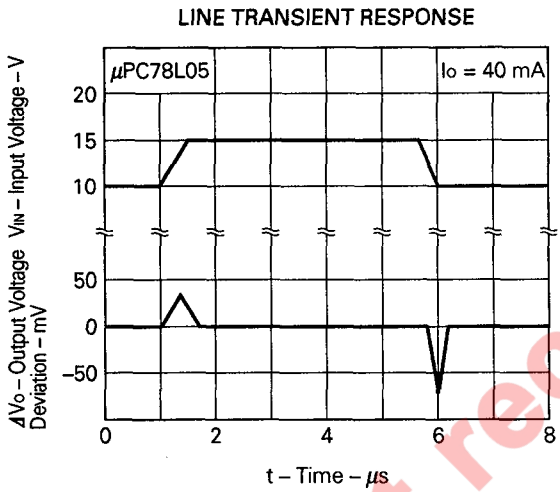
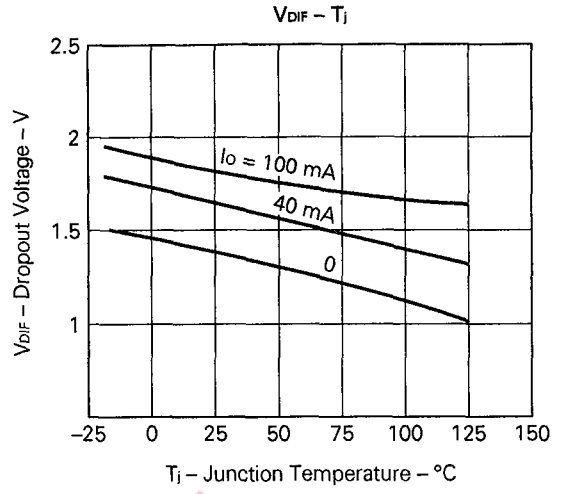
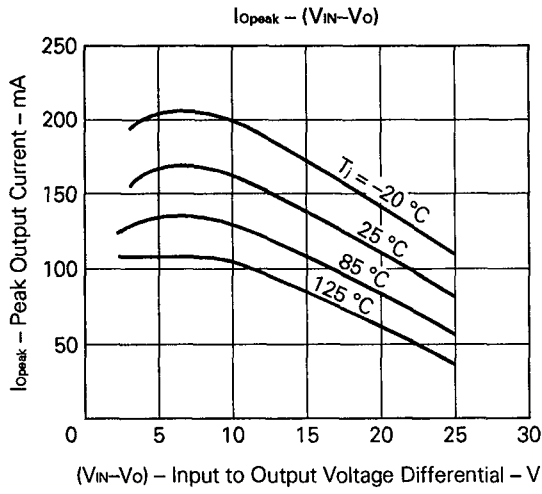
**ELECTRICAL CHARACTERISTICS μPC78L15**

( $V_{IN} = 23\text{ V}$ ,  $I_o = 40\text{ mA}$ ,  $0\text{ °C} \leq T_j \leq +125\text{ °C}$ ,  $C_{IN} = 0.33\text{ }\mu\text{F}$ ,  $C_{OUT} = 0.1\text{ }\mu\text{F}$ )

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Voltage	$V_o$	$T_j = 25\text{ °C}$	14.4	15	15.6	V
		$17.5\text{ V} \leq V_{IN} \leq 30\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$	14.25		15.75	
		$V_{IN} = 23\text{ V}$ , $1\text{ mA} \leq I_o \leq 70\text{ mA}$	14.25		15.75	
Line Regulation	REG <sub>IN</sub>	$T_j = 25\text{ °C}$ , $17.5\text{ V} \leq V_{IN} \leq 30\text{ V}$		18	300	mV
		$T_j = 25\text{ °C}$ , $20\text{ V} \leq V_{IN} \leq 30\text{ V}$		13	250	
Load Regulation	REG <sub>L</sub>	$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 100\text{ mA}$		25	150	mV
		$T_j = 25\text{ °C}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$		12	75	
Quiescent Current	$I_{BIAS}$	$T_j = 25\text{ °C}$		2.7	5.5	mA
Quiescent Current Change	$\Delta I_{BIAS}$	$20\text{ V} \leq V_{IN} \leq 30\text{ V}$ , $I_o = 40\text{ mA}$			1.5	mA
		$V_{IN} = 23\text{ V}$ , $1\text{ mA} \leq I_o \leq 40\text{ mA}$			0.1	
Output Noise Voltage	$V_n$	$T_j = 25\text{ °C}$ , $10\text{ Hz} \leq f \leq 100\text{ kHz}$		135	350	μV <sub>r.m.s.</sub>
Ripple Rejection	R · R	$T_j = 25\text{ °C}$ , $f = 120\text{ Hz}$ , $18.5\text{ V} \leq V_{IN} \leq 28.5\text{ V}$	45	61		dB
Dropout Voltage	$V_{DIF}$	$T_j = 25\text{ °C}$		1.7		V
Short Circuit Current	$I_{Oshort}$	$T_j = 25\text{ °C}$ , $V_{IN} = 30\text{ V}$		53		mA
Peak Output Current	$I_{Opeak}$	$T_j = 25\text{ °C}$	125	160	205	mA
Temperature coefficient of Output Voltage	$\Delta V_o / \Delta T$	$I_o = 5\text{ mA}$		1.4		mV/°C

TYPICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )



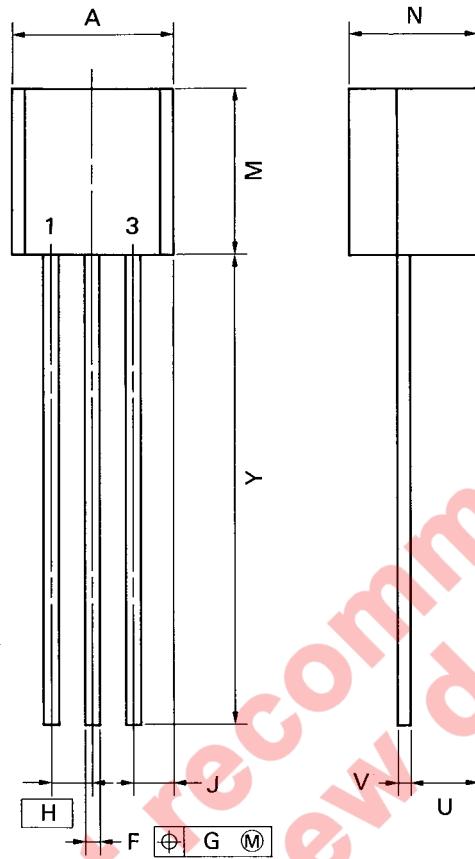


Not recommended for new design

**PACKAGE DIMENSIONS (Unit: mm)**

μPC78L00J Series

3 PIN PLASTIC SIP (TO-92)



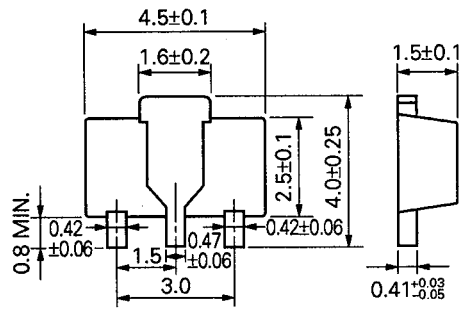
P3J-127B

**NOTE**

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
A	5.2 MAX.	0.205 MAX.
F	0.5 <sup>+0.1</sup>	0.02 <sup>+0.004</sup>
G	0.12	0.005
H	1.27	0.05
J	1.33 MAX.	0.053 MAX.
M	5.5 MAX.	0.217 MAX.
N	4.2 MAX.	0.166 MAX.
U	2.8 MAX.	0.111 MAX.
V	0.5 <sup>+0.1</sup>	0.02 <sup>+0.004</sup>
Y	15.0 <sup>+0.7</sup>	0.591 <sup>+0.028</sup>

μPC78L00T Series



Not recommend  
for new design

**RECOMMENDED SOLDERING CONDITIONS**

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

**<TYPES OF SURFACE MOUNT DEVICE>**

For more details, refer to our document "SMT MANUAL" (IEI-1207).

[μPC78L00T Series]

Soldering process	Soldering condition	Symbol
Infrared ray reflow	Peak package's surface temperature: 230 °C or below, Reflow time: 30 seconds or below (210 °C or higher), Number of reflow process: 1, Exposure limit*: None	IR30-00
VPS	Peak package's surface temperature: 215 °C or below, Reflow time: 40 seconds or below (200 °C or higher), Number of reflow process: 1, Exposure limit*: None	VP15-00

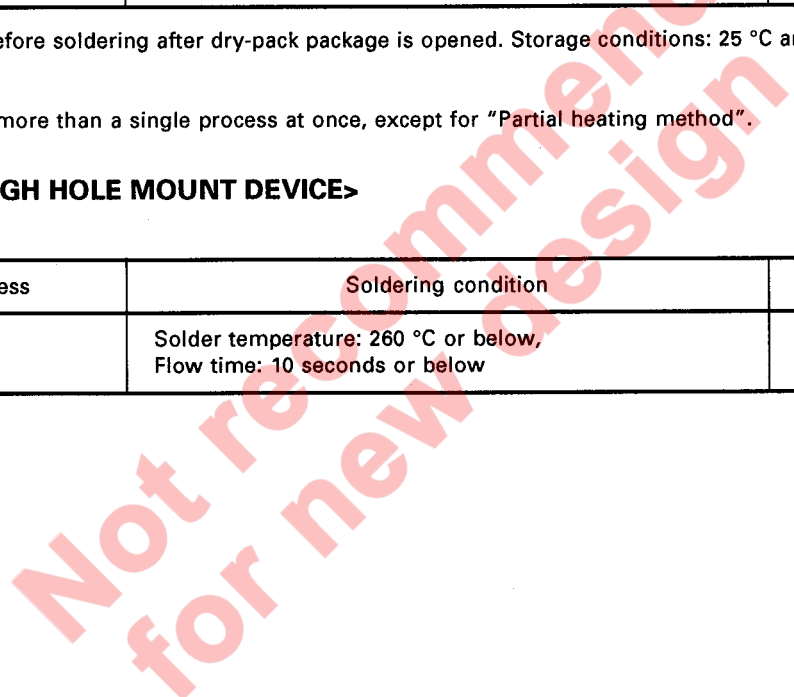
\*: Exposure limit before soldering after dry-pack package is opened. Storage conditions: 25 °C and relative humidity at 65% or less.

**Note:** Do not apply more than a single process at once, except for "Partial heating method".

**<TYPES OF THROUGH HOLE MOUNT DEVICE>**

[μPC78L00J Series]

Soldering process	Soldering condition	Symbol
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below	



**Reference**

Application note name	No.
Quality control of NEC semiconductor devices	TEI-1202
Quality control guide of semiconductor devices	MEI-1202
Assembly manual of semiconductor devices	IEI-1207
NEC semiconductor device reliability/quality control system	IEI-1212

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Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.